

NCE Automotive P-Channel Super Trench Power MOSFET

Description

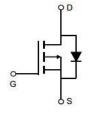
The NCEAP40P80K uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

- V_{DS} =-40V, I_D =-95A $R_{DS(ON)}$ =7.2m Ω (typical) @ V_{GS} =-10V $R_{DS(ON)}$ =11m Ω (typical) @ V_{GS} =-4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ∆Vds tested
- AEC-Q101 qualified

Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic Diagram



Marking and pin assignment



TO-252 -2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP40P80K	NCEAP40P80K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-40	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	lο	-95	А
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	-67	А
Pulsed Drain Current	I _{DM}	-360	А
Maximum Power Dissipation	P _D	150	W
Derating factor		1	W/°C
Single pulse avalanche energy (Note 1)	Eas	500	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

Thermal Resistance,Junction-to-Case	R _{θJC}	1.0	°C/W	
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	Source Breakdown Voltage BV _{DSS} V _{GS} =0V I _D =-250µA		-40	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	Igss	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.8	-1.4	-2.2	V
Dunin Course On State Besistance	D	V _{GS} =-10V, I _D =-20A	-	7.2	8.8	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-20A	-	11	14	mΩ
Forward Transconductance	g FS	V _{DS} =-5V,I _D =-20A	-	30	-	S
Dynamic Characteristics						
Input Capacitance	C _{lss}	\/ 00\/\\ 0\/	-	3700	-	pF
Output Capacitance	Coss	V _{DS} =-20V,V _{GS} =0V,	-	880	-	pF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	20	-	pF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	10.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =-20 V , I_{D} =-20 A	-	4	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_G =1.6 Ω	-	35	-	nS
Turn-Off Fall Time	t _f		-	5	-	nS
Total Gate Charge	Qg	\/ 00\/ L 00A	-	57	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-20V, I_{D} =-20A,	-	9.8	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	7.3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =-20A	-		-1.2	V
Diode Forward Current	Forward Current I _S		-	-	-95	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =-20A	-	-	24	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	-	68	nC

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=-20V,VG=-10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



Typical Electrical and Thermal Characteristics

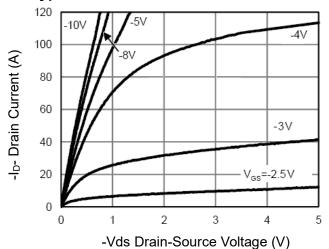


Figure 1 Output Characteristics

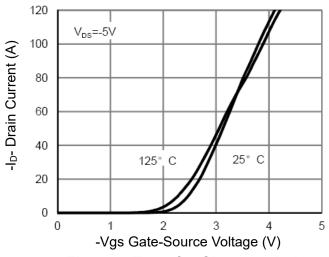


Figure 2 Transfer Characteristics

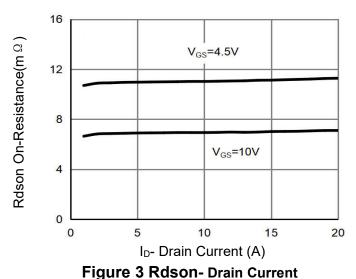


Figure 4 Rdson-JunctionTemperature

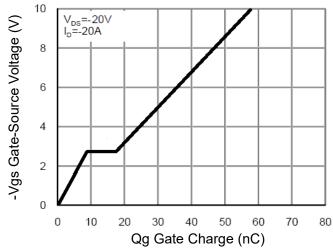


Figure 5 Gate Charge

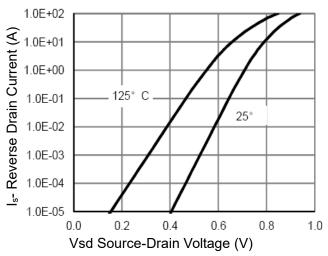


Figure 6 Source- Drain Diode Forward



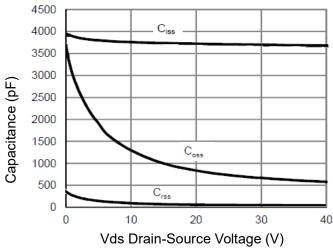


Figure 7 Capacitance vs Vds

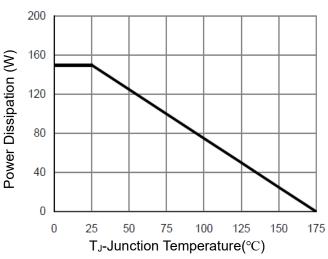


Figure 9 Power De-rating

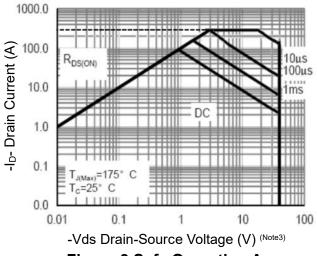


Figure 8 Safe Operation Area

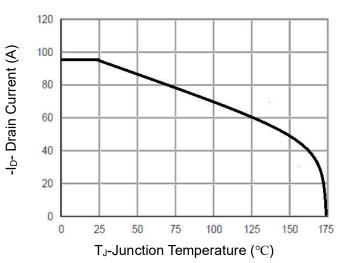


Figure 10 Current De-rating

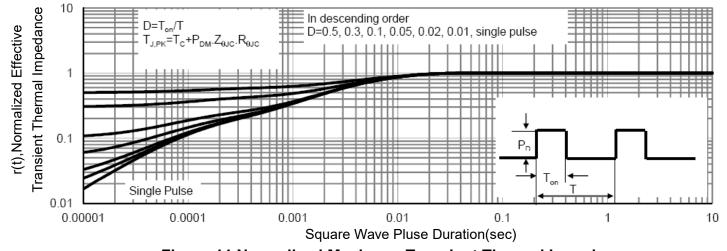
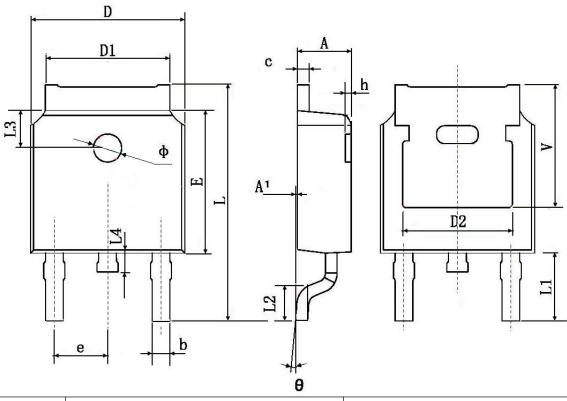


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
А	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.83	TYP.	0.190 TYP.			
E	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.900	TYP.	0.114 TYP.			
L2	1.400	1.700	0.055	0.067		
L3	1.600	TYP.	0.063	0.063 TYP.		
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350	TYP.	0.211).211 TYP.		

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NCEAP40P80K

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